Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|---|
| Ceramic and metal |
| Overall Length: |
| 0.096 inches |
| Overall Diameter: |
| 0.130 inches |
| Mounting Method: |
| Press fit |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 70.0 reverse voltage, peak |
| Current Rating Per Characteristic: |
| 200.00 milliamperes source cutoff current preset |
| Power Rating Per Characteristic: |
| 6.0 watts small-signal input power, common-collector preset |
| Maximum Operating Tempurature Per Measurement Point: |
| 200.0 degrees celsius junction |
| Precious Material And Location: |
| Metal parts of body surfaces gold |
| Precious Material: |
| Gold |
| Terminal Type And Quantity: |
| 2 ferrule |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |